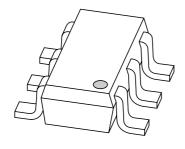
### DISCRETE SEMICONDUCTORS

# DATA SHEET



# PBSS5350D PNP transistor

**Product specification** 

2000 Mar 08





PNP transistor PBSS5350D

#### **FEATURES**

- · High current capabilities
- Low V<sub>CEsat</sub>.

#### **APPLICATIONS**

- Heavy duty battery powered equipment (Automotive, Telecom and Audio/Video) such as motor and lamp drivers
- V<sub>CEsat</sub> critical applications such as the latest low supply voltage IC applications
- All battery driven equipment to save battery power.

#### **DESCRIPTION**

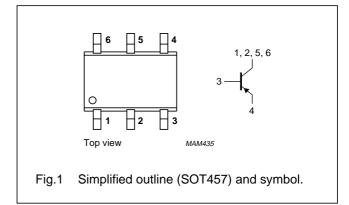
PNP low  $V_{\text{CEsat}}$  transistor in a SC-74 plastic package. NPN complement: PBSS4350D.

#### **MARKING CODE**

TYPE NUMBER	MARKING CODE
PBSS5350D	53

#### **PINNING**

PIN	DESCRIPTION				
1	collector				
2	collector				
3	base				
4	emitter				
5	collector				
6	collector				



#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	-60	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	-6	V
I <sub>C</sub>	collector current (DC)		_	-3	Α
I <sub>CM</sub>	peak collector current		_	-5	Α
I <sub>BM</sub>	peak base current		_	-1	Α
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C			
		note 1	_	600	mW
		note 2	_	750	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

#### Notes

- 1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm<sup>2</sup>.
- 2. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 6 cm<sup>2</sup>.

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#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to	in free air;		
	ambient	note 1	208	K/W
		note 2	160	K/W

#### **Notes**

- 1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm<sup>2</sup>.
- 2. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 6 cm<sup>2</sup>.

#### **CHARACTERISTICS**

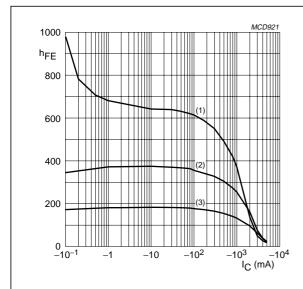
 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = -50 V	_	-100	nA
		$I_E = 0$ ; $V_{CB} = -50 \text{ V}$ ; $T_j = 150 ^{\circ}\text{C}$	_	-50	μΑ
I <sub>EBO</sub>	emitter cut-off current	$I_C = 0; V_{EB} = -5 V$	_	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = −2 V;			
		$I_C = -500 \text{ mA}$	200	_	
		$I_{C} = -1 \text{ A}$ ; note 1	200	_	
		$I_C = -2 A$ ; note 1	100	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -500 \text{ mA}; I_B = -50 \text{ mA}$	_	-100	mV
		$I_C = -1 \text{ A}; I_B = -50 \text{ mA}$	_	-180	mV
		$I_C = -2 \text{ A}$ ; $I_B = -200 \text{ mA}$ ; note 1	_	-300	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C = -2 \text{ A}$ ; $I_B = -200 \text{ mA}$ ; note 1	_	-1.2	V
V <sub>BEon</sub>	base-emitter turn-on voltage	$I_C = -1 \text{ A}; V_{CE} = -2 \text{ V}; \text{ note } 1$	_	-1.1	V
Cc	collector capacitance	$I_E = I_e = 0$ ; $V_{CB} = -10 \text{ V}$ ; $f = 1 \text{ MHz}$	_	40	pF
f <sub>T</sub>	transition frequency	$I_C = -100 \text{ mA}; V_{CE} = -5 \text{ V};$ f = 100 MHz	100	_	MHz

#### Note

1. Pulse test  $t_p \le 300~\mu s,~\delta \le 0.02.$ 

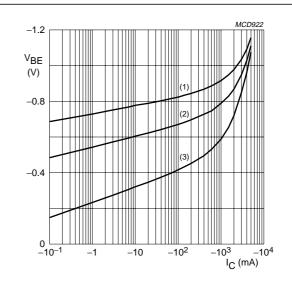
PNP transistor PBSS5350D



 $V_{CE} = -2 V$ .

- (1)  $T_{amb} = 150 \, ^{\circ}C$ .
- (2)  $T_{amb} = 25 \, ^{\circ}C$ .
- (3)  $T_{amb} = -55 \, ^{\circ}C$ .

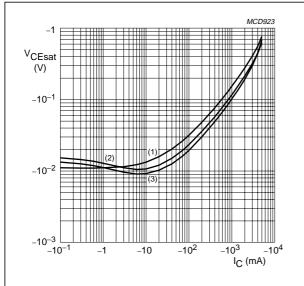
Fig.2 DC current gain as a function of collector current.



 $V_{CE} = -2 \text{ V}.$ 

- (1)  $T_{amb} = 150 \, ^{\circ}C$ .
- (2)  $T_{amb} = 25 \, ^{\circ}C$ .
- (3)  $T_{amb} = -55 \, ^{\circ}C$ .

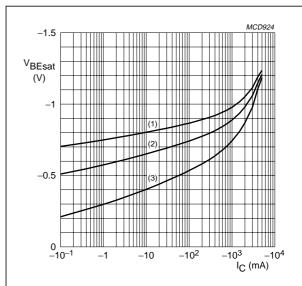
Fig.3 Base-emitter voltage as a function of collector current.



 $I_{\rm C}/I_{\rm B}=10.$ 

- (1)  $T_{amb} = 150 \, ^{\circ}C$ .
- (2)  $T_{amb} = 25 \, ^{\circ}C$ .
- (3)  $T_{amb} = -55 \, ^{\circ}C$ .

Fig.4 Collector-emitter saturation voltage as a function of collector current.

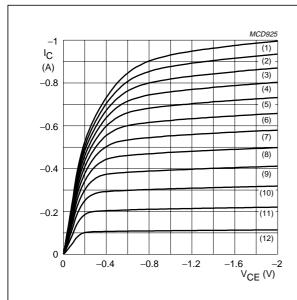


 $I_{\rm C}/I_{\rm B} = 10$ .

- (1)  $T_{amb} = -55 \,^{\circ}C$ .
- (2)  $T_{amb} = 25 \, ^{\circ}C$ .
- (3)  $T_{amb} = 150 \, ^{\circ}C$ .

Fig.5 Base-emitter saturation voltage as a function of collector current.

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 $T_{amb} = 25 \, ^{\circ}C.$ 

(1)  $I_B = -3.96 \text{ mA}.$ 

(7)  $I_B = -1.98 \text{ mA}.$ 

(2)  $I_B = -3.63 \text{ mA}.$ 

(8)  $I_B = -1.65 \text{ mA}.$ 

(3)  $I_B = -3.3 \text{ mA}.$ 

(9)  $I_B = -1.32 \text{ mA}.$ 

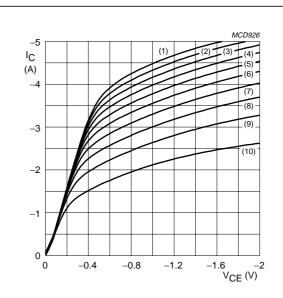
(4)  $I_B = -2.97 \text{ mA}.$ 

(10)  $I_B = -990 \mu A$ . (11)  $I_B = -660 \mu A$ .

(5)  $I_B = -2.64 \text{ mA}.$ (6)  $I_B = -2.31 \text{ mA}.$ 

(12)  $I_B = -330 \,\mu\text{A}$ .

Fig.6 Collector current as a function of base current and collector-emitter voltage.



 $T_{amb} = 25 \, ^{\circ}C.$ 

(1)  $I_B = -250 \text{ mA}.$ 

(6)  $I_B = -125 \text{ mA}.$ 

(2)  $I_B = -225 \text{ mA}.$ 

(7)  $I_B = -100 \text{ mA}.$ 

(3)  $I_B = -200 \text{ mA}.$ 

(8)  $I_B = -75 \text{ mA}.$ 

(4)  $I_B = -175 \text{ mA}.$ 

(9)  $I_B = -50 \text{ mA}.$ 

(5)  $I_B = -150 \text{ mA}$ .

(10)  $I_B = -25 \text{ mA}$ .

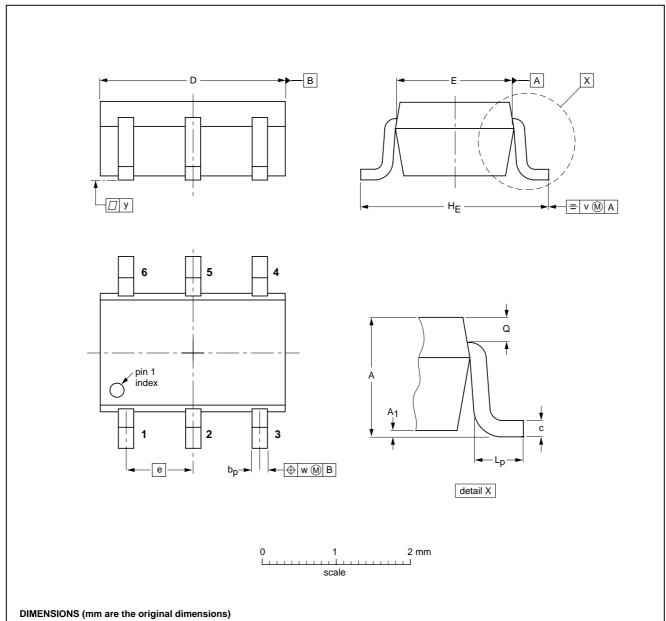
Fig.7 Collector current as a function of base current and collector-emitter voltage.

PNP transistor PBSS5350D

#### PACKAGE OUTLINE

#### Plastic surface mounted package; 6 leads

**SOT457** 



UNIT	Α	A <sub>1</sub>	bp	С	D	E	е	HE	Lp	Q	v	w	у
mm	1.1 0.9	0.1 0.013	0.40 0.25	0.26 0.10	3.1 2.7	1.7 1.3	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2	0.1

OUTLINE		REFERENCES				ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT457			SC-74			97-02-28

PNP transistor PBSS5350D

#### **DEFINITIONS**

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				

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